



- Tentative Specification
- Preliminary Specification
- Specification Approval

Specification For SID 2.90” BWR EPD

Model Name: JS0290YN01-TNG-A0

Version:V0.2

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CUSTOMER APPROVAL	SIGNATURE	DATE
	Notes:	

Notes :

- 1、 Please contact SID before assigning your product based on this module specification.
- 2、 To improve the quality of product, and this product specification is subject to change without any notice.

CONTENTS

1. Over View	4
2. Features	4
3. Mechanical Specification	4
4. Mechanical Drawing of EPD module	5
5. Input /Output Pin Assignment.....	6-7
6. Electrical Characteristics	7
6.1 Absolute Maximum Rating.....	7
6.2 Panel DC Characteristics	8
6.3 Panel DC Characteristics (Driver IC Internal Regulators)	9-10
6.4 Timing Characteristics	11
7. Optical Specifications	12
8. Handling, Safety, and Environment Requirements	12
9. Reliability Test	13
10. Block Diagram.....	14
11. Typical Application Circuit with SPI Interface.....	15
12. Typical Operating Sequence.....	16
13. Part Number Definition.....	17
14. Inspection condition.....	17

1. Over View

SE0290YN01-TNG-A0 is an Active Matrix Electrophoretic Display (AM EPD), with interface and a reference system design. The 2.9inch active area contains 296×128 pixels. The module is a TFT-array driving electrophoresis display, with integrated circuits including gate driver, source driver, MCU interface, timing controller, oscillator, DC-DC, SRAM, LUT, VCOM. Module can be used in portable electronic devices, such as Electronic Shelf Label (ESL) System.

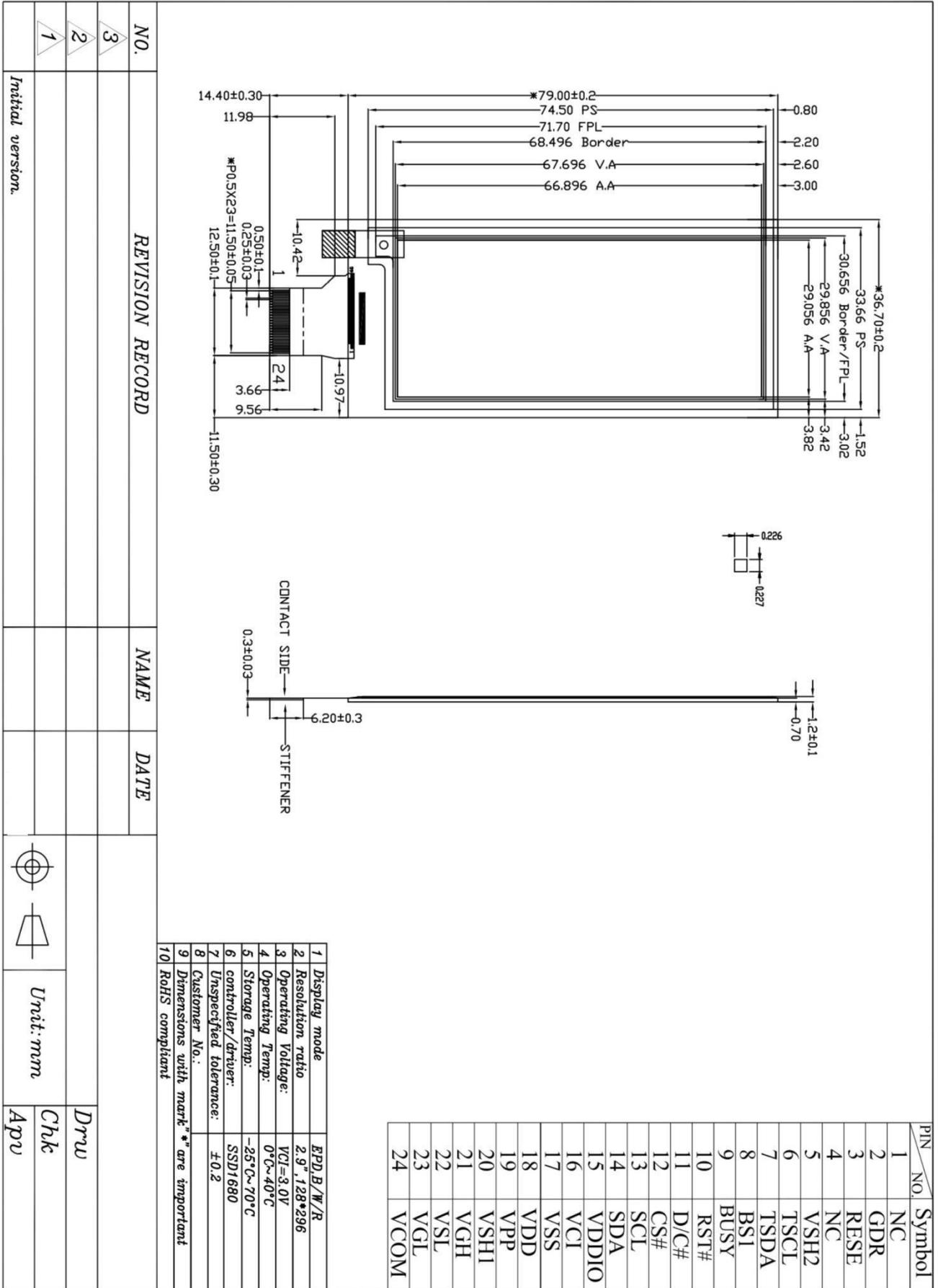
2.Features

- 296×128 pixels display
- High contrast High reflectance
- Ultra wide viewing angle Ultra low power consumption
- Pure reflective mode
- Bi-stable display
- Commercial temperature range
- Landscape portrait modes
- Hard-coat antiglare display surface
- Ultra Low current deep sleep mode
- On chip display RAM
- Waveform can stored in On-chip OTP or written by MCU
- Serial peripheral interface available
- On-chip oscillator
- On-chip booster and regulator control for generating VCOM, Gate and Source driving voltage
- I²C signal master interface to read external temperature sensor
- Built-in temperature sensor

3. Mechanical Specifications

Parameter	Specifications	Unit	Remark
Screen Size	2.9	Inch	
Display Resolution	128(H)×296(V)	Pixel	DPI:112
Active Area	29.056×66.896	mm	
Pixel Pitch	0.227×0.226	mm	
Pixel Configuration	Rectangle		
Outline Dimension	36.7(H)×79.0 (V) ×1.20(D)	mm	
Weight	5.5±0.5	g	

4. Mechanical Drawing of EPD module



5. Input /Output Pin Assignment

No.	Name	I/O	Description	Remark
1	NC		Do not connect with other NC pins	Keep Open
2	GDR	O	N-Channel MOSFET Gate Drive Control	
3	RESE	I	Current Sense Input for the Control Loop	
4	NC	NC	Do not connect with other NC pins	Keep Open
5	VSH2	C	Positive Source driving voltage(Red)	
6	TSCL	O	I ² C Interface to digital temperature sensor Clock pin	
7	TSDA	I/O	I ² C Interface to digital temperature sensor Data pin	
8	BS1	I	Bus Interface selection pin	Note 5-5
9	BUSY	O	Busy state output pin	Note 5-4
10	RES#	I	Reset signal input. Active Low.	Note 5-3
11	D/C#	I	Data /Command control pin	Note 5-2
12	CS#	I	Chip select input pin	Note 5-1
13	SCL	I	Serial Clock pin (SPI)	
14	SDA	I/O	Serial Data pin (SPI)	
15	VDDIO	P	Power Supply for interface logic pins It should be connected with VCI	
16	VCI	P	Power Supply for the chip	
17	VSS	P	Ground	
18	VDD	C	Core logic power pin VDD can be regulated internally from VCI. A capacitor should be connected between VDD and VSS	
19	VPP	P	FOR TEST	
20	VSH1	C	Positive Source driving voltage	
21	VGH	C	Power Supply pin for Positive Gate driving voltage and VSH1	
22	VSL	C	Negative Source driving voltage	
23	VGL	C	Power Supply pin for Negative Gate driving voltage VCOM and VSL	
24	VCOM	C	VCOM driving voltage	

- I = Input Pin, O =Output Pin, I/O = Bi-directional Pin (Input/output), P = Power Pin, C = Capacitor Pin
- Note 5-1: This pin (CS#) is the chip select input connecting to the MCU. The chip is enabled for MCU communication only when CS# is pulled LOW.
- Note 5-2: This pin is (D/C#) Data/Command control pin connecting to the MCU in 4-wire SPI mode. When the pin is pulled HIGH, the data at SDA will be interpreted as data. When the pin is pulled LOW, the data at SDA will be interpreted as command.
- Note 5-3: This pin (RES#) is reset signal input. The Reset is active low.
- Note 5-4: This pin is Busy state output pin. When Busy is High, the operation of chip should not be interrupted, command should not be sent. The chip would put Busy pin High when -Outputting display waveform -Communicating with digital temperature sensor
- Note 5-5: Bus interface selection pin

BS1 State	MCU Interface
L	4-lines serial peripheral interface(SPI) - 8 bits SPI
H	3- lines serial peripheral interface(SPI) - 9 bits SPI

6. Electrical Characteristics

6.1 Absolute Maximum Rating

Parameter	Symbol	Rating	Unit
Logic supply voltage	VCI	-0.5 to +4.0	V
Logic Input voltage	VIN	-0.5 to VCI +0.5	V
Logic Output voltage	VOUT	-0.5 to VCI +0.5	V
Operating Temp range	TOPR	0 to +40	°C
Storage Temp range	TSTG	-25 to+70	°C
Optimal Storage Temp	TSTGo	23±2	°C
Optimal Storage Humidity	HSTGo	55±10	%RH

Note:

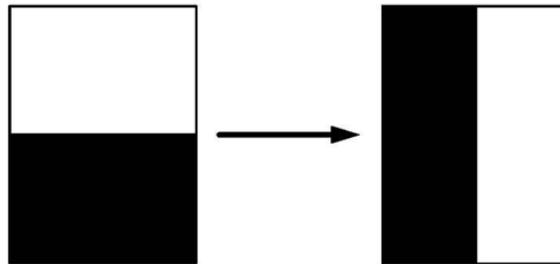
Maximum ratings are those values beyond which damages to the device may occur. Functional operation should be restricted to the limits in the Panel DC Characteristics tables.

6.2 Panel DC Characteristics

The following specifications apply for: VSS=0V, VCI=3.0V, TOPR =25°C.

Parameter	Symbol	Conditions	Applicable pin	Min.	Typ.	Max	Units
Single ground	V _{SS}	-		-	0	-	V
Logic supply voltage	V _{CI}	-	VCI	2.2	3.0	3.7	V
Core logic voltage	V _{DD}		VDD	1.7	1.8	1.9	V
High level input voltage	V _{IH}	-	-	0.8 V _{CI}	-	-	V
Low level input voltage	V _{IL}	-	-	-	-	0.2 V _{CI}	V
High level output voltage	V _{OH}	IOH = -100uA	-	0.9 VCI	-	-	V
Low level output voltage	V _{OL}	IOL = 100uA	-	-	-	0.1 V _{CI}	V
Typical power	P _{TYP}	V _{CI} =3.0V	-	-	TBD	-	mW
Deep sleep mode	P _{STPY}	V _{CI} =3.0V	-	-	0.00 3	-	mW
Typical operating current	Iopr_VCI	V _{CI} =3.0V	-	-	TBD	-	mA
Image update time	-	25 °C	-	-	12	-	sec
Sleep mode current	Islp_VCI	DC/DC off No clock No input load Ram data retain	-	-	20		uA
Deep sleep mode current	Idslp_VCI	DC/DC off No clock No input load Ram data not retain	-	-	1	5	uA

Notes: 1. The typical power is measured with following transition from horizontal 2 scale pattern to vertical 2 scale pattern.



2. The deep sleep power is the consumed power when the panel controller is in deep sleep mode.
3. The listed electrical/optical characteristics are only guaranteed under the controller & waveform provided by SID.

6.3 Panel AC Characteristics

6.3.1 MCU Interface Selection

The pin assignment at different interface mode is summarized in Table 6-4-1. Different MCU mode can be set by hardware selection on BS1 pins. The display panel only supports 4-wire SPI or 3-wire SPI interface mode.

Pin Name	Data/Command Interface		Control Signal		
	SDA	SCL	CS#	D/C#	RES#
Bus interface	SDA	SCL	CS#	D/C#	RES#
BS1=L 4-wire SPI	SDA	SCL	CS#	D/C#	RES#
BS1=H 3-wire SPI	SDA	SCL	CS#	L	RES#

6.3.2 MCU Serial Interface (4-wire SPI)

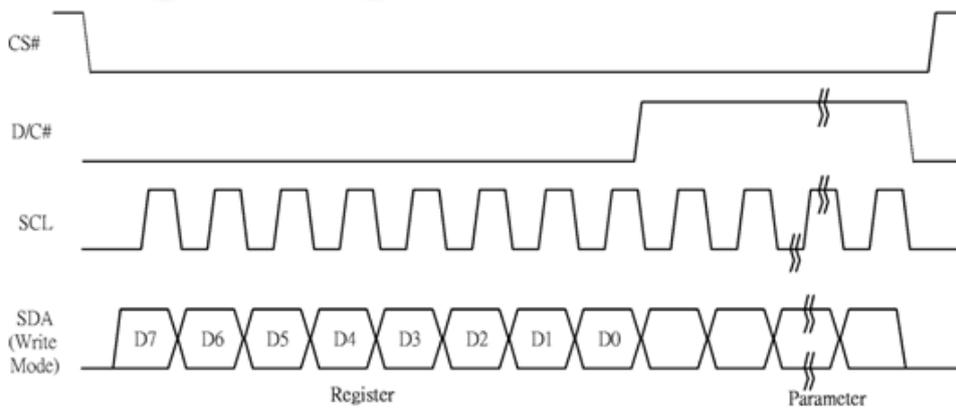
The serial interface consists of serial clock SCL, serial data SDA, D/C#, CS#. This interface supports Write mode and Read mode.

Function	CS#	D/C#	SCL
Write command	L	L	↑
Write data	L	H	↑

Note: ↑ stands for rising edge of signal

In the write mode SDA is shifted into an 8-bit shift register on every rising edge of SCL in the order of D7, D6, ... D0. The level of D/C# should be kept over the whole byte. The data byte in the shift register is written to the Graphic Display Data RAM /Data Byte register or command Byte register according to D/C# pin.

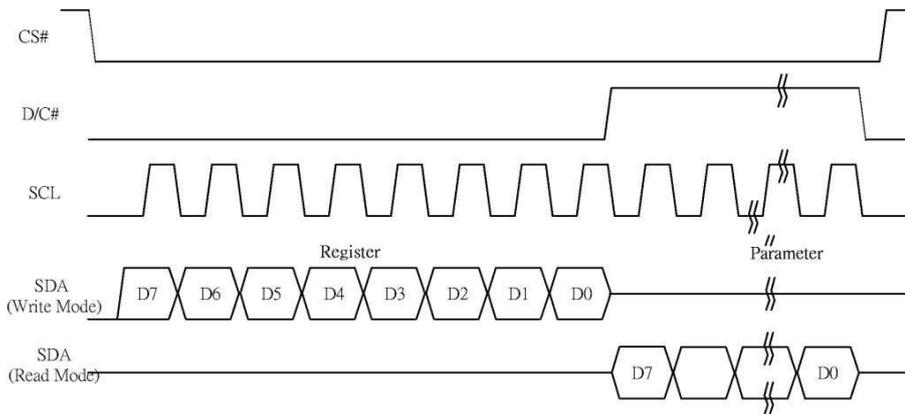
Figure 6-1: Write procedure in 4-wire SPI mode



In the Read mode:

1. After driving CS# to low, MCU need to define the register to be read.
2. SDA is shifted into an 8-bit shift register on every rising edge of SCL in the order of D7, D6, ... D0 with D/C# keep low.
3. After SCL change to low for the last bit of register, D/C# need to drive to high.
4. SDA is shifted out an 8-bit data on every falling edge of SCL in the order of D7, D6, ... D0.
5. Depending on register type, more than 1 byte can be read out. After all byte are read, CS# need to drive to high to stop the read operation.

Figure 6-2: Read procedure in 4-wire SPI mode



6.3.3 MCU Serial Interface (3-wire SPI)

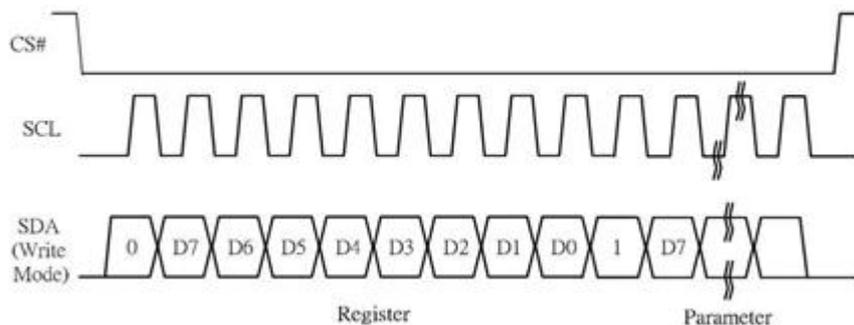
The 3-wire serial interface consists of serial clock SCL, serial data SDA and CS#. This interface also supports Write mode and Read mode.

The operation is similar to 4-wire serial interface while D/C# pin is not used. There are altogether 9-bits will be shifted into the shift register on every ninth clock in sequence: D/C# bit, D7 to D0 bit. The D/C# bit (first bit of the sequential data) will determine the following data byte in the shift register is written to the Display Data RAM (D/C# bit = 1) or the command register (D/C# bit = 0).

Function	CS#	D/C#	SCL
Write command	L	Tie	↑
Write data	L	Tie	↑

Note: ↑ stands for rising edge of signal

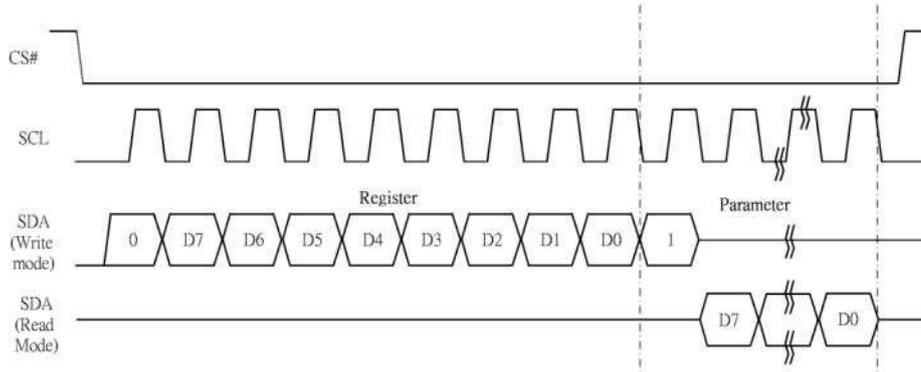
Figure 6-3: Write procedure in 3-wire SPI mode



7 In the Read mode:

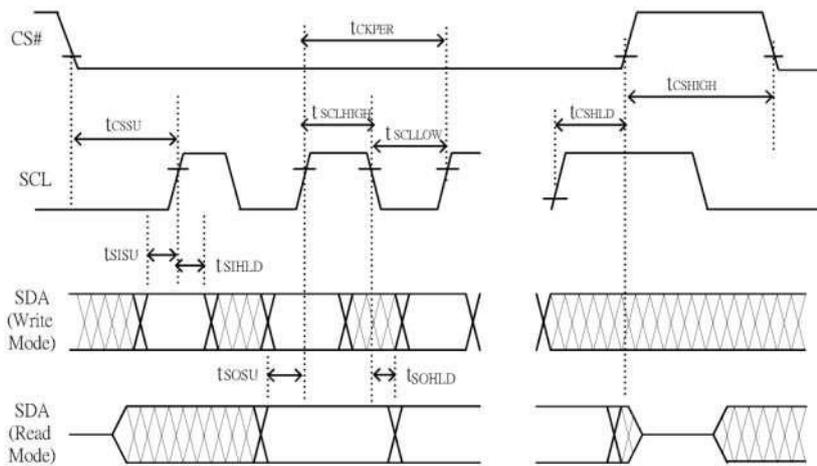
- 1 After driving CS# to low, MCU need to define the register to be read.
- 2 D/C=0 is shifted thru SDA with one rising edge of SCL
- 3 SDA is shifted into an 8-bit shift register on every rising edge of SCL in the order of D7, D6, ... D0.
- 4 D/C=1 is shifted thru SDA with one rising edge of SCL
- 5 SDA is shifted out an 8-bit data on every falling edge of SCL in the order of D7, D6, ... D0.
- 6 Depending on register type, more than 1 byte can be read out. After all byte are read, CS# need to drive to high to stop the read operation.

Figure 6-4: Read procedure in 3-wire SPI mode



6.3.4 Interface Timing

The following specifications apply for: VSS=0V, VCI=3.0V, TOPR =25°C.



Changed Diagram

Serial Interface Timing Characteristics

(VCI - VSS = 2.2V to 3.7V, TOPR = 25°C, CL=20pF)

Write mode

Symbol	Parameter	Min	Typ	Max	Unit
f _{SCL}	SCL frequency (Write Mode)			20	MHz
t _{CSSU}	Time CS# has to be low before the first rising edge of SCLK	60			ns
t _{CSSL}	Time CS# has to remain low after the last falling edge of SCLK	65			ns
t _{CSPER}	Time CS# has to remain low after the last falling edge of SCLK	65			ns
t _{CSHIGH}	Time CS# has to remain high between two transfers	100			ns
t _{SCLHIGH}	Part of the clock period where SCL has to remain high	25			ns
t _{SCLLOW}	Part of the clock period where SCL has to remain low	25			ns
t _{SISU}	Time SI (SDA Write Mode) has to be stable before the next rising edge of SCL	10			ns
t _{SIHLD}	Time SI (SDA Write Mode) has to remain stable after the rising edge of SCL	40			ns

Read mode

Symbol	Parameter	Min	Typ	Max	Unit
f _{SCL}	SCL frequency (Read Mode)			2.5	MHz
t _{CSSU}	Time CS# has to be low before the first rising edge of SCLK	100			ns
t _{CSSL}	Time CS# has to remain low after the last falling edge of SCLK	50			ns
t _{CSPER}	Time CS# has to remain low after the last falling edge of SCLK	50			ns
t _{CSHIGH}	Time CS# has to remain high between two transfers	250			ns
t _{SCLHIGH}	Part of the clock period where SCL has to remain high	180			ns
t _{SCLLOW}	Part of the clock period where SCL has to remain low	180			ns
t _{SOSU}	Time SO (SDA Read Mode) will be stable before the next rising edge of SCL		50		ns
t _{SOHLD}	Time SO (SDA Read Mode) will remain stable after the falling edge of SCL		0		ns

7. Optical Specifications

Measurements are made with that the illumination is under an angle of 45 degree, the detection is perpendicular unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ.	Max	Units	Notes
R	White Reflectivity	White	30	35	-	%	8-1
CR	Contrast Ratio	Indoor	8:1		-		8-2
GN	2Grey Level	-		$DS+(WS-DS)*n(m-1)$			8-3
T update	Image update time	at 25 °C		12	-	sec	
Life		Topr		1000000times or 5years			

Notes: 8-1. Luminance meter: Eye-One Pro Spectrophotometer.

8-2. CR=Surface Reflectance with all white pixel/Surface Reflectance with all black pixels. 8-3 WS: White state, DS: Dark state

8. Handling, Safety and Environment Requirements

Warning

The display glass may break when it is dropped or bumped on a hard surface. Handle with care. Should the display break, do not touch the electrophoretic material. In case of contact with electrophoretic material, wash with water and soap.

Caution

The display module should not be exposed to harmful gases, such as acid and alkali gases, which corrode electronic components. Disassembling the display module.

Disassembling the display module can cause permanent damage and invalidates the warranty agreements.

Observe general precautions that are common to handling delicate electronic components. The glass can break and front surfaces can easily be damaged. Moreover the display is sensitive to static electricity and other rough environmental conditions.

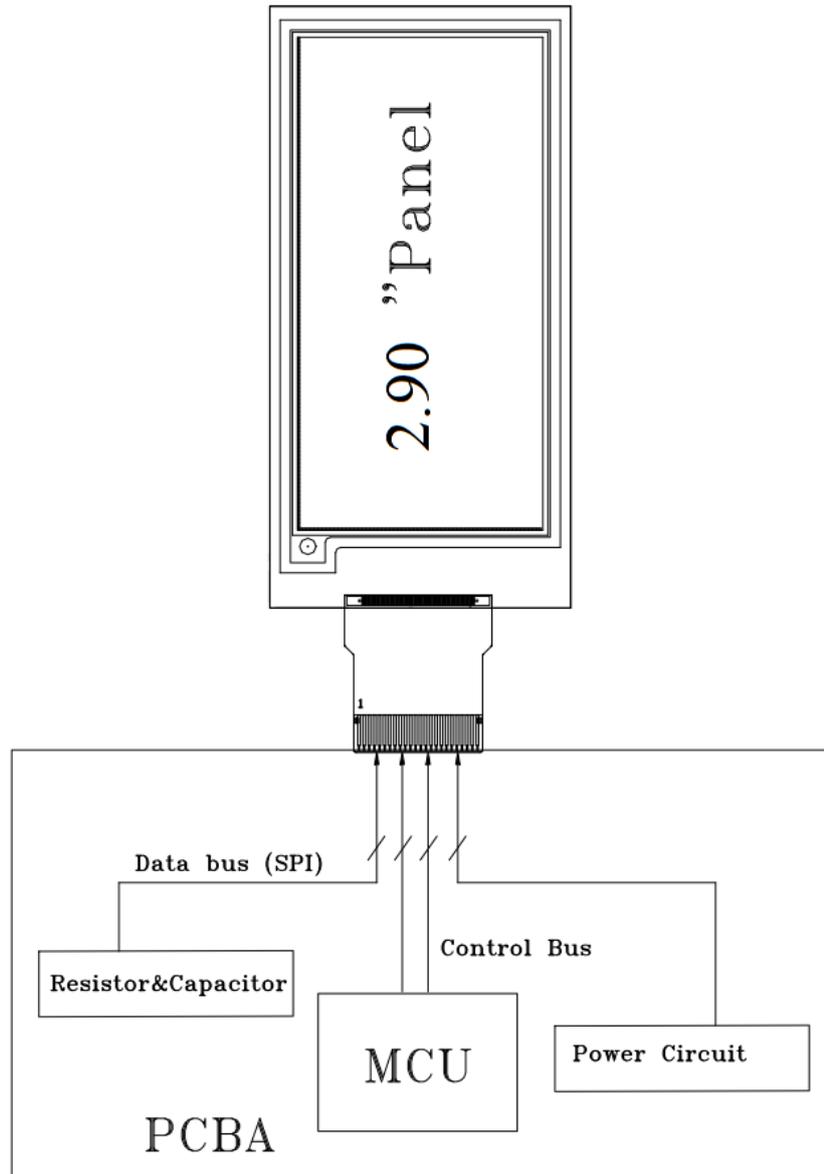
Data sheet status	
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

9. Reliability test

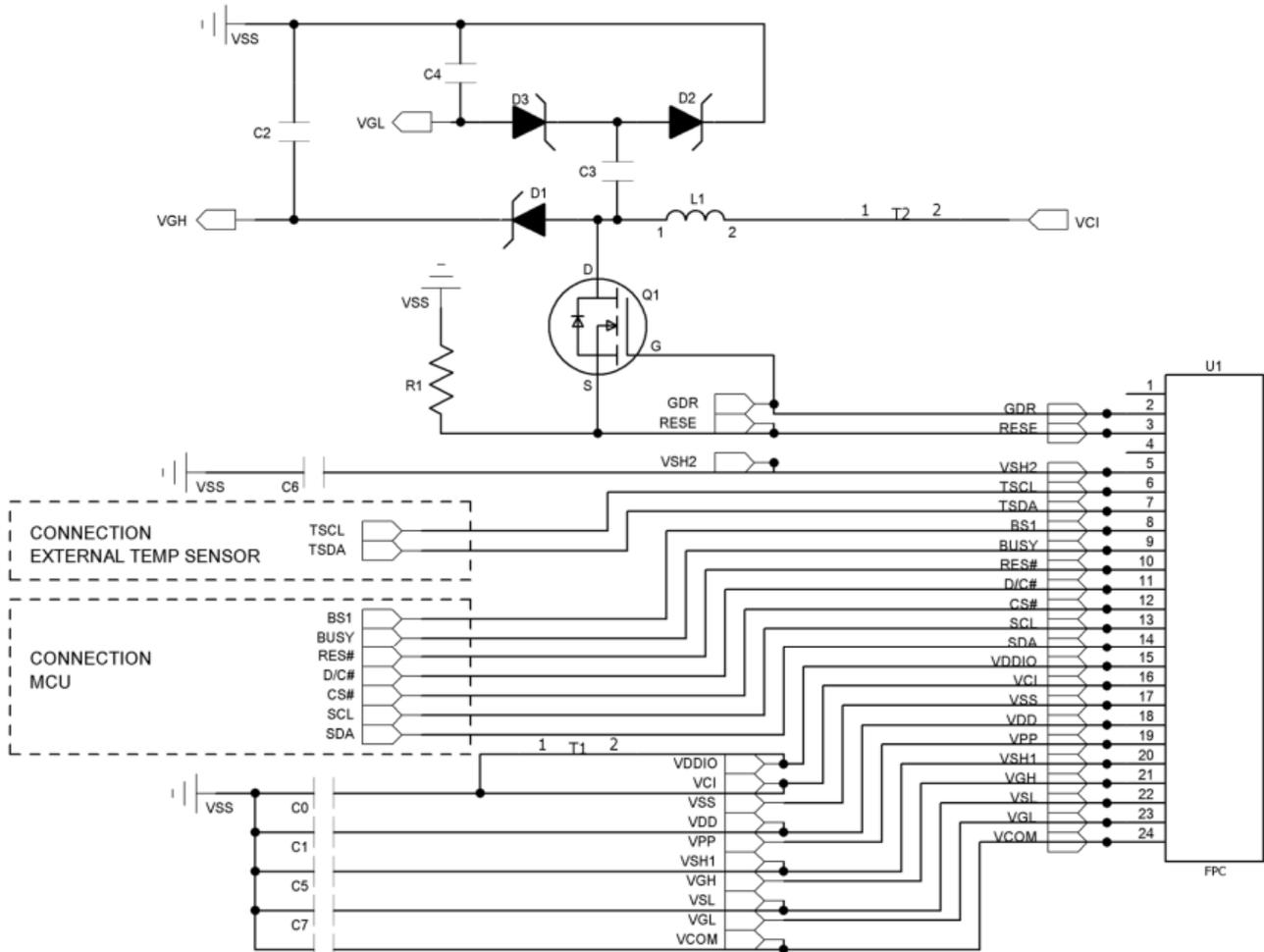
NO	Test items	Test condition
1	Low-Temperature Storage	T = -25°C, 240 h Test in white pattern
2	High-Temperature Storage	T=70°C, RH=40%, 240h Test in white pattern
3	High-Temperature Operation	T=40°C, RH=35%, 240h
4	Low-Temperature Operation	0°C, 240h
5	High-Temperature, High-Humidity Operation	T=40°C, RH=80%, 240h
6	High Temperature, High Humidity Storage	T=50°C, RH=80%, 240h Test in white pattern
7	Temperature Cycle	1 cycle:[-25°C 30min]→[+70 °C 30 min] : 50 cycles Test in white pattern
8	UV exposure Resistance	765W/m ² for 168hrs,40 °C Test in white pattern
9	ESD Gun	Air+/-15KV;Contact+/-8KV (Test finished product shell, not display only) Air+/-8KV;Contact+/-6KV (Naked EPD display, no including IC and FPC area) Air+/-4KV;Contact+/-2KV (Naked EPD display, including IC and FPC area)

Note: Put in normal temperature for 1hour after test finished, display performance is ok.

10. Block Diagram



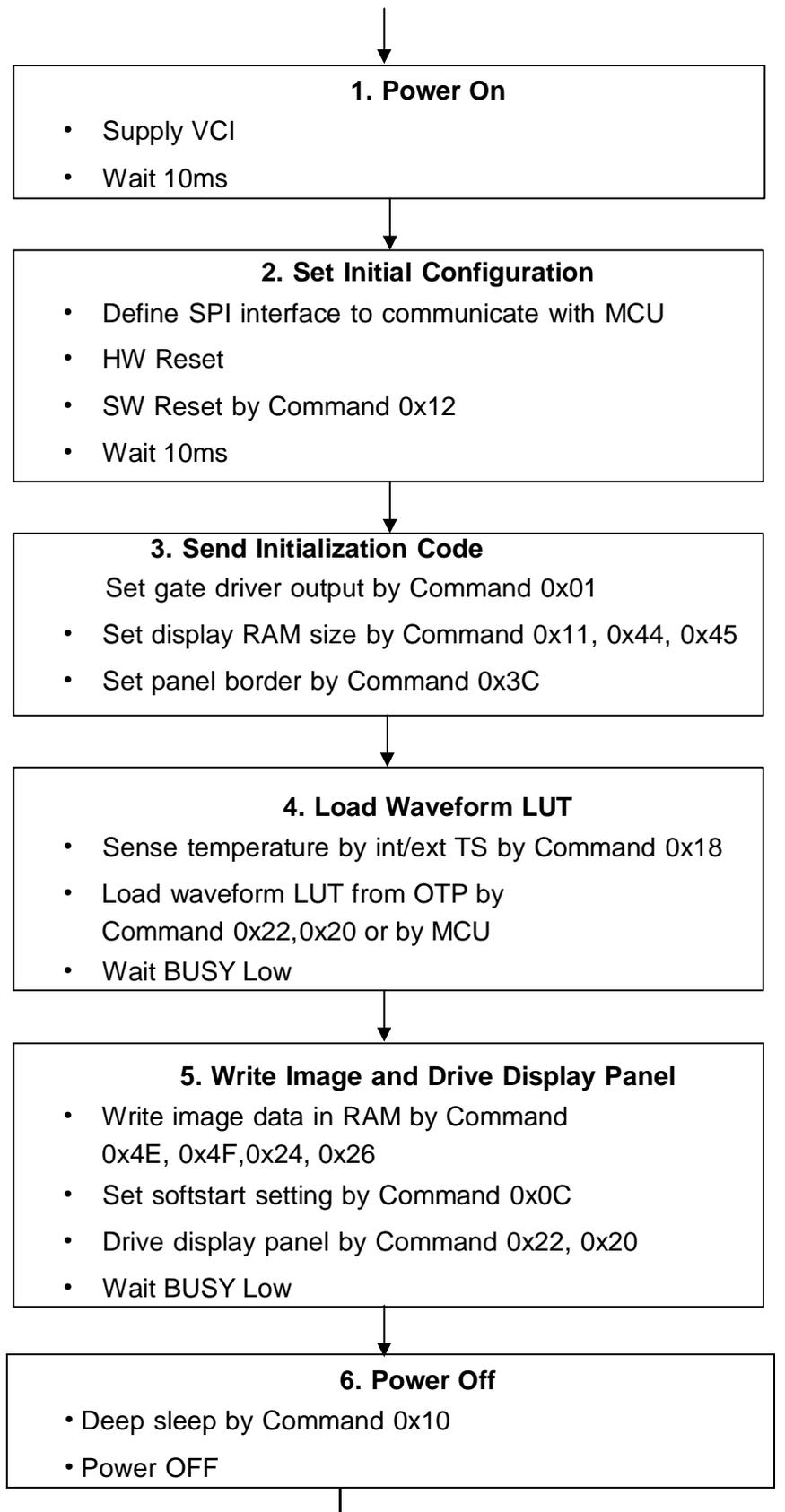
11. Typical Application Circuit with SPI Interface



Part Name	Value	Requirements/Reference Part
C0-C1	1uF	X5R/X7R; Voltage Rating : 6V or 25V
C2-C7	1uF	0402/0603/0805; X5R/X7R; Voltage Rating : 25V
C8	0.47uF, 1uF	0603/0805; X7R; Voltage Rating : 25V Note: Effective capacitance > 0.25uF @ 18V DC bias
R1	2.2 ohm	0402, 0603, 0805; 1% variation, ≥ 0.05W
D1-D3	Diode	MBR0530 1) Reverse DC voltage ≥ 30V 2) I _o ≥ 500mA 3) Forward voltage ≤ 430mV
Q1	NMOS	Si1304BDL/NX3008NBK 1) Drain-Source breakdown voltage ≥ 30V 2) V _{gs(th)} = 0.9V (Typ), 1.3V (Max) 3) R _{ds on} ≤ 2.1Ω @ V _{gs} = 2.5V
L1	47uH	CDRH2D18 / LDNP-470NC I _o = 500mA (Max)
U1	0.5mm ZIF socket	24pins, 0.5mm pitch

12. Typical Operating Sequence

12.1 Normal Operation Flow



12.2 Normal Operation Reference Program Code

TBD

13. Part Number Definition

TBD

14. Inspection condition

14.1 Environment

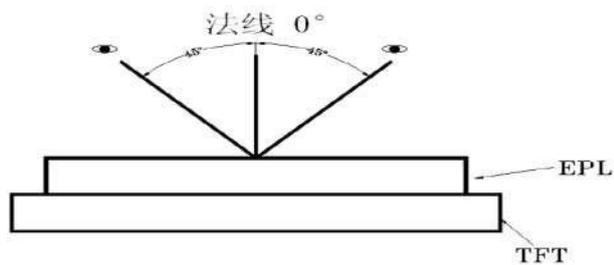
Temperature: $25\pm 3^{\circ}\text{C}$

Humidity: $55\pm 10\%\text{RH}$

14.2 Illuminance

Brightness: $1200\sim 1500\text{LUX}$; distance: $20\text{-}30\text{CM}$; Angle: Relate 30° surround.

14.3 Inspection method



14.4 Display area

